Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-107-3734

Inclosure Material:
Glass
Terminal Length:
1.100 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
68.2 breakdown voltage, dc
Current Rating Per Characteristic:
20.00 milliamperes forward current, total rms nanoamperes
Power Rating Per Characteristic:
1500.0 watts small-signal input power, common-collector of standard range
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0